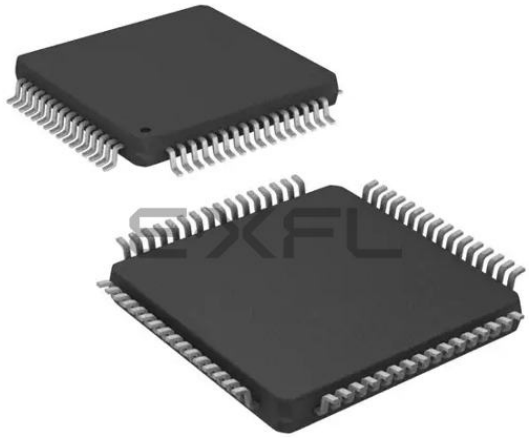
Silicon Labs - EFM32TG11B540F64IQ64-AR Datasheet



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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I²C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, LCD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TJ)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b540f64iq64-ar

1. Feature List

The EFM32TG11 highlighted features are listed below.

- **ARM Cortex-M0+ CPU platform**
  - High performance 32-bit processor @ up to 48 MHz
  - Memory Protection Unit
  - Wake-up Interrupt Controller
- **Flexible Energy Management System**
  - 37 µA/MHz in Active Mode (EM0)
  - 1.30 µA EM2 Deep Sleep current (8 kB RAM retention and RTCC running from LFRCO)
- **Integrated DC-DC buck converter**
- **Backup Power Domain**
  - RTCC and retention registers in a separate power domain, available in all energy modes
  - Operation from backup battery when main power absent/ insufficient
- **Up to 128 kB flash program memory**
- **Up to 32 kB RAM data memory**
- **Communication Interfaces**
  - CAN Bus Controller
    - Version 2.0A and 2.0B up to 1 Mbps
  - 4 × Universal Synchronous/Asynchronous Receiver/ Transmitter
    - UART/SPI/SmartCard (ISO 7816)/IrDA/I2S/LIN
    - Triple buffered full/half-duplex operation with flow control
    - Ultra high speed (24 MHz) operation on one instance
  - 1 × Universal Asynchronous Receiver/ Transmitter
  - 1 × Low Energy UART
    - Autonomous operation with DMA in Deep Sleep Mode
  - 2 × I^2C Interface with SMBus support
    - Address recognition in EM3 Stop Mode
- **Up to 67 General Purpose I/O Pins**
  - Configurable push-pull, open-drain, pull-up/down, input filter, drive strength
  - Configurable peripheral I/O locations
  - 5 V tolerance on select pins
  - Asynchronous external interrupts
  - Output state retention and wake-up from Shutoff Mode
- **Up to 8 Channel DMA Controller**
- **Up to 8 Channel Peripheral Reflex System (PRS) for autonomous inter-peripheral signaling**
- **Hardware Cryptography**
  - AES 128/256-bit keys
  - ECC B/K163, B/K233, P192, P224, P256
  - SHA-1 and SHA-2 (SHA-224 and SHA-256)
  - True Random Number Generator (TRNG)
- **Hardware CRC engine**
  - Single-cycle computation with 8/16/32-bit data and 16-bit (programmable)/32-bit (fixed) polynomial
- **Security Management Unit (SMU)**
  - Fine-grained access control for on-chip peripherals
- **Integrated Low-energy LCD Controller with up to 8 × 32 segments**
  - Voltage boost, contrast and autonomous animation
  - Patented low-energy LCD driver
- **Ultra Low-Power Precision Analog Peripherals**
  - 12-bit 1 Msamples/s Analog to Digital Converter (ADC)
    - On-chip temperature sensor
  - 2 × 12-bit 500 ksamples/s Digital to Analog Converter (VDAC)
  - Up to 2 × Analog Comparator (ACMP)
  - Up to 4 × Operational Amplifier (OPAMP)
  - Robust current-based capacitive sensing with up to 38 inputs and wake-on-touch (CSEN)
  - Up to 62 GPIO pins are analog-capable. Flexible analog peripheral-to-pin routing via Analog Port (APORT)
  - Supply Voltage Monitor

3. System Overview

3.1 Introduction

The Tiny Gecko Series 1 product family is well suited for any battery operated application as well as other systems requiring high performance and low energy consumption. This section gives a short introduction to the MCU system. The detailed functional description can be found in the Tiny Gecko Series 1 Reference Manual. Any behavior that does not conform to the specifications in this data sheet or the functional descriptions in the Tiny Gecko Series 1 Reference Manual are detailed in the EFM32TG11 Errata document.

A block diagram of the Tiny Gecko Series 1 family is shown in Figure 3.1 Detailed EFM32TG11 Block Diagram on page 10. The diagram shows a superset of features available on the family, which vary by OPN. For more information about specific device features, consult Ordering Information.

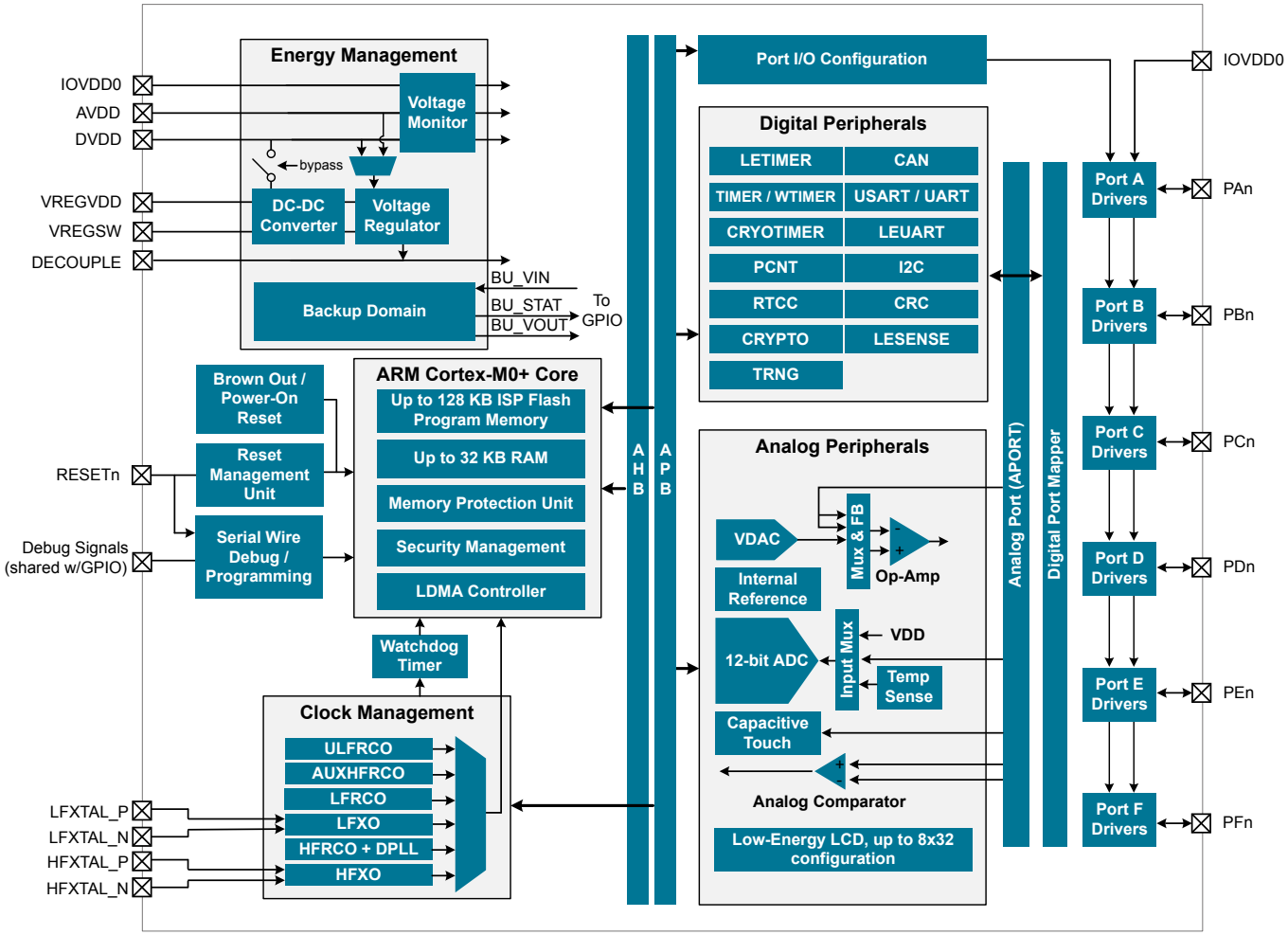


Figure 3.1. Detailed EFM32TG11 Block Diagram

4. Electrical Specifications

4.1 Electrical Characteristics

All electrical parameters in all tables are specified under the following conditions, unless stated otherwise:

- Typical values are based on T_{AMB}=25 °C and V_{DD}= 3.3 V, by production test and/or technology characterization.
- Minimum and maximum values represent the worst conditions across supply voltage, process variation, and operating temperature, unless stated otherwise.

Refer to 4.1.2.1 General Operating Conditions for more details about operational supply and temperature limits.

4.1.1 Absolute Maximum Ratings

Stresses above those listed below may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at http://www.silabs.com/support/quality/pages/default.aspx.

Table 4.1. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Storage temperature range	T_{STG}		-50	—	150	°C
Voltage on any supply pin	V_{DDMAX}		-0.3	—	3.8	V
Voltage ramp rate on any supply pin	$V_{DDRAMPMAX}$		—	—	1	V / µs
DC voltage on any GPIO pin	V_{DIGPIN}	5V tolerant GPIO pins[1 2 3]	-0.3	—	Min of 5.25 and IOVDD +2	V
		LCD pins[3]	-0.3	—	Min of 3.8 and IOVDD +2	V
		Standard GPIO pins	-0.3	—	IOVDD+0.3	V
Total current into VDD power lines	I_{VDDMAX}	Source	—	—	200	mA
Total current into VSS ground lines	I_{VSSMAX}	Sink	—	—	200	mA
Current per I/O pin	I_{IOMAX}	Sink	—	—	50	mA
		Source	—	—	50	mA
Current for all I/O pins	$I_{IOALLMAX}$	Sink	—	—	200	mA
		Source	—	—	200	mA
Junction temperature	T_J	-G grade devices	-40	—	105	°C
		-I grade devices	-40	—	125	°C

Note:

1. When a GPIO pin is routed to the analog module through the APORT, the maximum voltage = IOVDD.
2. Valid for IOVDD in valid operating range or when IOVDD is undriven (high-Z). If IOVDD is connected to a low-impedance source below the valid operating range (e.g. IOVDD shorted to VSS), the pin voltage maximum is IOVDD + 0.3 V, to avoid exceeding the maximum IO current specifications.
3. To operate above the IOVDD supply rail, over-voltage tolerance must be enabled according to the GPIO_Px_OVTDIS register. Pins with over-voltage tolerance disabled have the same limits as Standard GPIO.

4.1.4 DC-DC Converter

Test conditions: L_DCDC=4.7 µH (Murata LQH3NPN4R7MM0L), C_DCDC=4.7 µF (Samsung CL10B475KQ8NQNC), V_DCDC_I=3.3 V, V_DCDC_O=1.8 V, I_DCDC_LOAD=50 mA, Heavy Drive configuration, F_DCDC_LN=7 MHz, unless otherwise indicated.

Table 4.4. DC-DC Converter

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input voltage range	V_{DCDC_I}	Bypass mode, I_{DCDC_LOAD} = 50 mA	1.8	—	$V_{VREGVDD\_MAX}$	V
		Low noise (LN) mode, 1.8 V output, I_{DCDC_LOAD} = 100 mA, or Low power (LP) mode, 1.8 V output, I_{DCDC_LOAD} = 10 mA	2.4	—	$V_{VREGVDD\_MAX}$	V
		Low noise (LN) mode, 1.8 V output, I_{DCDC_LOAD} = 200 mA	2.6	—	$V_{VREGVDD\_MAX}$	V
Output voltage programmable range[1]	V_{DCDC_O}		1.8	—	$V_{VREGVDD}$	V
Regulation DC accuracy	ACC_{DC}	Low Noise (LN) mode, 1.8 V target output	TBD	—	TBD	V
Regulation window[4]	WIN_{REG}	Low Power (LP) mode, LPCMPBIASEMxx[3] = 0, 1.8 V target output, I_{DCDC_LOAD} ≤ 75 µA	TBD	—	TBD	V
		Low Power (LP) mode, LPCMPBIASEMxx[3] = 3, 1.8 V target output, I_{DCDC_LOAD} ≤ 10 mA	TBD	—	TBD	V
Steady-state output ripple	V_R		—	3	—	mVpp
Output voltage under/overshoot	V_{OV}	CCM Mode (LNFORCECCM[3] = 1), Load changes between 0 mA and 100 mA	—	25	TBD	mV
		DCM Mode (LNFORCECCM[3] = 0), Load changes between 0 mA and 10 mA	—	45	TBD	mV
		Overshoot during LP to LN CCM/DCM mode transitions compared to DC level in LN mode	—	200	—	mV
		Undershoot during BYP/LP to LN CCM (LNFORCECCM[3] = 1) mode transitions compared to DC level in LN mode	—	40	—	mV
		Undershoot during BYP/LP to LN DCM (LNFORCECCM[3] = 0) mode transitions compared to DC level in LN mode	—	100	—	mV
DC line regulation	V_{REG}	Input changes between $V_{VREGVDD\_MAX}$ and 2.4 V	—	0.1	—	%
DC load regulation	I_{REG}	Load changes between 0 mA and 100 mA in CCM mode	—	0.1	—	%

4.1.8 Brown Out Detector (BOD)

Table 4.10. Brown Out Detector (BOD)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
DVDD BOD threshold	$V_{DVDDBOD}$	DVDD rising	—	—	TBD	V
		DVDD falling (EM0/EM1)	TBD	—	—	V
		DVDD falling (EM2/EM3)	TBD	—	—	V
DVDD BOD hysteresis	$V_{DVDDBOD\_HYST}$		—	18	—	mV
DVDD BOD response time	$t_{DVDDBOD\_DELAY}$	Supply drops at 0.1V/µs rate	—	2.4	—	µs
AVDD BOD threshold	$V_{AVDDBOD}$	AVDD rising	—	—	TBD	V
		AVDD falling (EM0/EM1)	TBD	—	—	V
		AVDD falling (EM2/EM3)	TBD	—	—	V
AVDD BOD hysteresis	$V_{AVDDBOD\_HYST}$		—	20	—	mV
AVDD BOD response time	$t_{AVDDBOD\_DELAY}$	Supply drops at 0.1V/µs rate	—	2.4	—	µs
EM4 BOD threshold	$V_{EM4DBOD}$	AVDD rising	—	—	TBD	V
		AVDD falling	TBD	—	—	V
EM4 BOD hysteresis	V_{EM4BOD_HYST}		—	25	—	mV
EM4 BOD response time	t_{EM4BOD_DELAY}	Supply drops at 0.1V/µs rate	—	300	—	µs

4.1.9.2 High-Frequency Crystal Oscillator (HFXO)

Table 4.12. High-Frequency Crystal Oscillator (HFXO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Crystal frequency	f_{HFXO}		4	—	48	MHz
Supported crystal equivalent series resistance (ESR)	ESR_{HFXO}	48 MHz crystal	—	—	50	Ω
		24 MHz crystal	—	—	150	Ω
		4 MHz crystal	—	—	180	Ω
Supported range of crystal load capacitance[1]	C_{HFXO_CL}		TBD	—	TBD	pF
Nominal on-chip tuning cap range[2]	C_{HFXO_T}	On each of HFXTAL_N and HFXTAL_P pins	8.7	—	51.7	pF
On-chip tuning capacitance step	SS_{HFXO}		—	0.08	—	pF
Startup time	t_{HFXO}	48 MHz crystal, ESR = 50 Ohm, C_L = 8 pF	—	350	—	µs
		24 MHz crystal, ESR = 150 Ohm, C_L = 6 pF	—	700	—	µs
		4 MHz crystal, ESR = 180 Ohm, C_L = 18 pF	—	3	—	ms
Current consumption after startup	I_{HFXO}	48 MHz crystal	—	880	—	µA
		24 MHz crystal	—	420	—	µA
		4 MHz crystal	—	80	—	µA

Note:

1. Total load capacitance as seen by the crystal.
2. The effective load capacitance seen by the crystal will be C_{HFXO_T} /2. This is because each XTAL pin has a tuning cap and the two caps will be seen in series by the crystal.

4.1.9.3 Low-Frequency RC Oscillator (LFRCO)

Table 4.13. Low-Frequency RC Oscillator (LFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Oscillation frequency	f_{LFRCO}	ENVREF[2] = 1	TBD	32.768	TBD	kHz
		ENVREF[2] = 1, T > 85 °C	TBD	32.768	TBD	kHz
		ENVREF[2] = 0	TBD	32.768	TBD	kHz
Startup time	t_{LFRCO}		—	500	—	µs
Current consumption [1]	I_{LFRCO}	ENVREF = 1 in CMU_LFRCOCTRL	—	370	—	nA
		ENVREF = 0 in CMU_LFRCOCTRL	—	520	—	nA

Note:
1. Block is supplied by AVDD if ANASW = 0, or DVDD if ANASW=1 in EMU_PWRCTRL register.
2. In CMU_LFRCOCTRL register.

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency limits	f_{HFRCO_BAND}	FREQRANGE = 0, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 3, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 6, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 7, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 8, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 10, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 11, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 12, FINETUNINGEN = 0	TBD	—	TBD	MHz
		FREQRANGE = 13, FINETUNINGEN = 0	TBD	—	TBD	MHz

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Open-loop gain	G_{OL}	DRIVESTRENGTH = 3	—	135	—	dB
		DRIVESTRENGTH = 2	—	137	—	dB
		DRIVESTRENGTH = 1	—	121	—	dB
		DRIVESTRENGTH = 0	—	109	—	dB
Loop unit-gain frequency[7]	UGF	DRIVESTRENGTH = 3, Buffer connection	—	3.38	—	MHz
		DRIVESTRENGTH = 2, Buffer connection	—	0.9	—	MHz
		DRIVESTRENGTH = 1, Buffer connection	—	132	—	kHz
		DRIVESTRENGTH = 0, Buffer connection	—	34	—	kHz
		DRIVESTRENGTH = 3, 3x Gain connection	—	2.57	—	MHz
		DRIVESTRENGTH = 2, 3x Gain connection	—	0.71	—	MHz
		DRIVESTRENGTH = 1, 3x Gain connection	—	113	—	kHz
		DRIVESTRENGTH = 0, 3x Gain connection	—	28	—	kHz
Phase margin	PM	DRIVESTRENGTH = 3, Buffer connection	—	67	—	°
		DRIVESTRENGTH = 2, Buffer connection	—	69	—	°
		DRIVESTRENGTH = 1, Buffer connection	—	63	—	°
		DRIVESTRENGTH = 0, Buffer connection	—	68	—	°
Output voltage noise	N_{OUT}	DRIVESTRENGTH = 3, Buffer connection, 10 Hz - 10 MHz	—	146	—	µVrms
		DRIVESTRENGTH = 2, Buffer connection, 10 Hz - 10 MHz	—	163	—	µVrms
		DRIVESTRENGTH = 1, Buffer connection, 10 Hz - 1 MHz	—	170	—	µVrms
		DRIVESTRENGTH = 0, Buffer connection, 10 Hz - 1 MHz	—	176	—	µVrms
		DRIVESTRENGTH = 3, 3x Gain connection, 10 Hz - 10 MHz	—	313	—	µVrms
		DRIVESTRENGTH = 2, 3x Gain connection, 10 Hz - 10 MHz	—	271	—	µVrms
		DRIVESTRENGTH = 1, 3x Gain connection, 10 Hz - 1 MHz	—	247	—	µVrms
		DRIVESTRENGTH = 0, 3x Gain connection, 10 Hz - 1 MHz	—	245	—	µVrms

4.1.22 USART SPI

SPI Master Timing

Table 4.31. SPI Master Timing

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCLK period [1] [3] [2]	t_{SCLK}		2 * $t_{HFPERCLK}$	—	—	ns
CS to MOSI [1] [3]	t_{CS_MO}		-19.8	—	18.9	ns
SCLK to MOSI [1] [3]	t_{SCLK_MO}		-10	—	14.5	ns
MISO setup time [1] [3]	t_{SU_MI}	IOVDD = 1.62 V	75	—	—	ns
		IOVDD = 3.0 V	40	—	—	ns
MISO hold time [1] [3]	t_{H_MI}		-10	—	—	ns

Note:
1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).
2. $t_{HFPERCLK}$ is one period of the selected HFPERCLK.
3. Measurement done with 8 pF output loading at 10% and 90% of V_{DD} (figure shows 50% of V_{DD}).

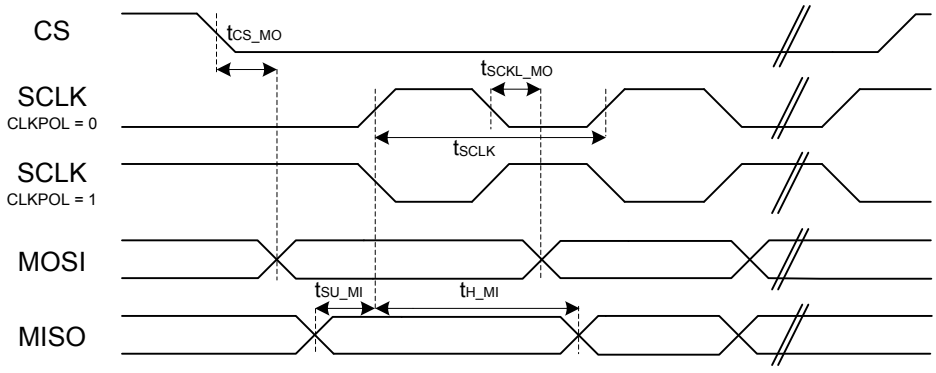


Figure 4.1. SPI Master Timing Diagram

4.2.1 Supply Current

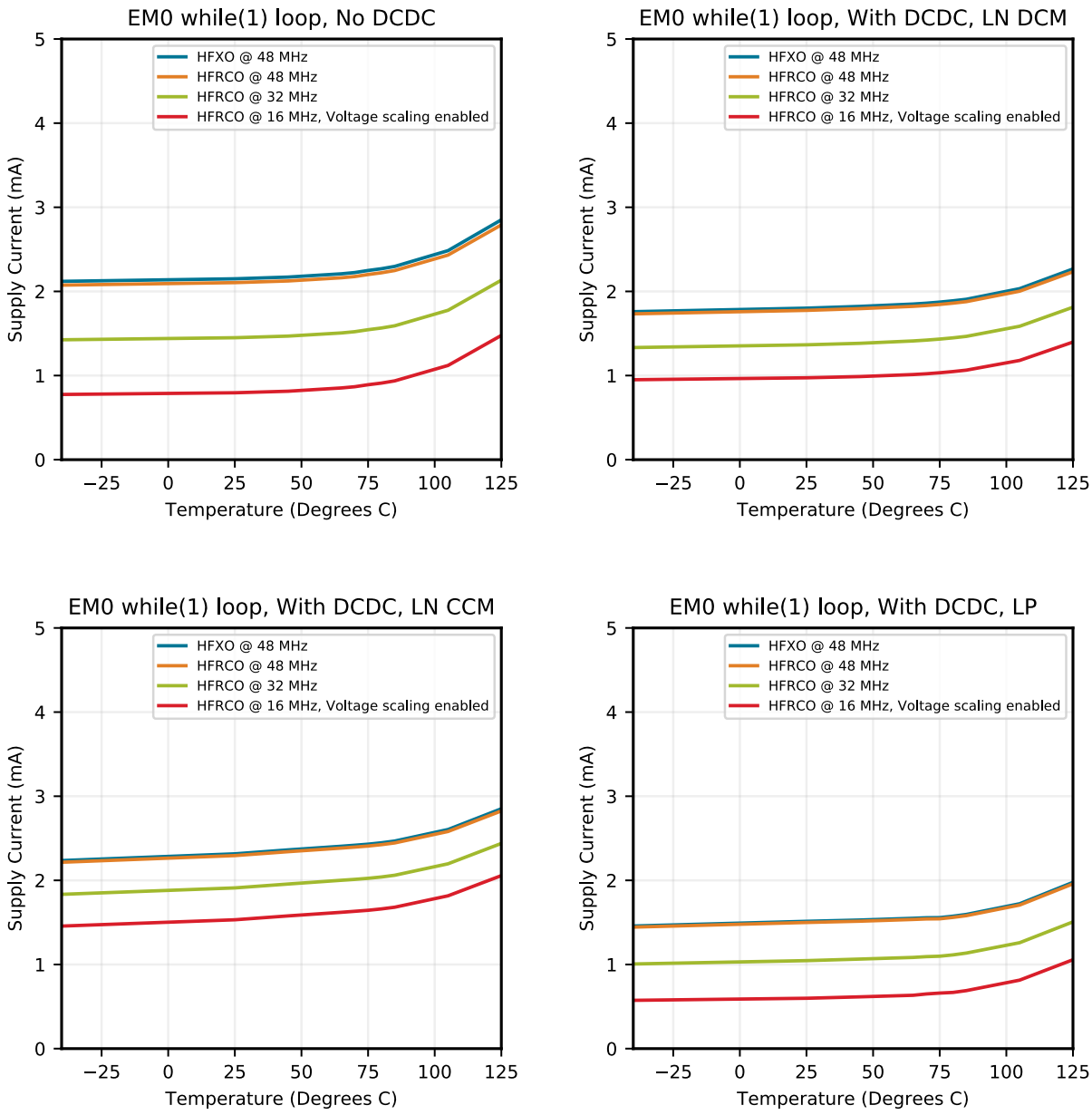


Figure 4.3. EM0 Active Mode Typical Supply Current vs. Temperature

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB4	10	GPIO	PB5	11	GPIO
PB6	12	GPIO	PC0	13	GPIO (5V)
PC1	14	GPIO (5V)	PC2	15	GPIO (5V)
PC3	16	GPIO (5V)	PC4	17	GPIO
PC5	18	GPIO	PB7	19	GPIO
PB8	20	GPIO	PA8	21	GPIO
PA9	22	GPIO	PA10	23	GPIO
PA12	24	GPIO	PA13	25	GPIO (5V)
PA14	26	GPIO	RESETn	27	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	28	GPIO	PB12	29	GPIO
AVDD	30 34	Analog power supply.	PB13	31	GPIO
PB14	32	GPIO	PD0	35	GPIO (5V)
PD1	36	GPIO	PD2	37	GPIO (5V)
PD3	38	GPIO	PD4	39	GPIO
PD5	40	GPIO	PD6	41	GPIO
PD7	42	GPIO	PD8	43	GPIO
PC6	44	GPIO	PC7	45	GPIO
VREGSW	47	DCDC regulator switching node	VREGVDD	48	Voltage regulator VDD input
DVDD	49	Digital power supply.	DECOUPLE	50	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	52	GPIO	PE5	53	GPIO
PE6	54	GPIO	PE7	55	GPIO
PC8	56	GPIO	PC9	57	GPIO
PC10	58	GPIO (5V)	PC11	59	GPIO (5V)
PC12	60	GPIO (5V)	PC13	61	GPIO (5V)
PC14	62	GPIO (5V)	PC15	63	GPIO (5V)
PF0	64	GPIO (5V)	PF1	65	GPIO (5V)
PF2	66	GPIO	PF3	67	GPIO
PF4	68	GPIO	PF5	69	GPIO
PE8	71	GPIO	PE9	72	GPIO
PE10	73	GPIO	PE11	74	GPIO
BODEN	75	Brown-Out Detector Enable. This pin may be left disconnected or tied to AVDD.	PE12	76	GPIO
PE13	77	GPIO	PE14	78	GPIO

5.9 EFM32TG11B5xx in QFP48 Device Pinout

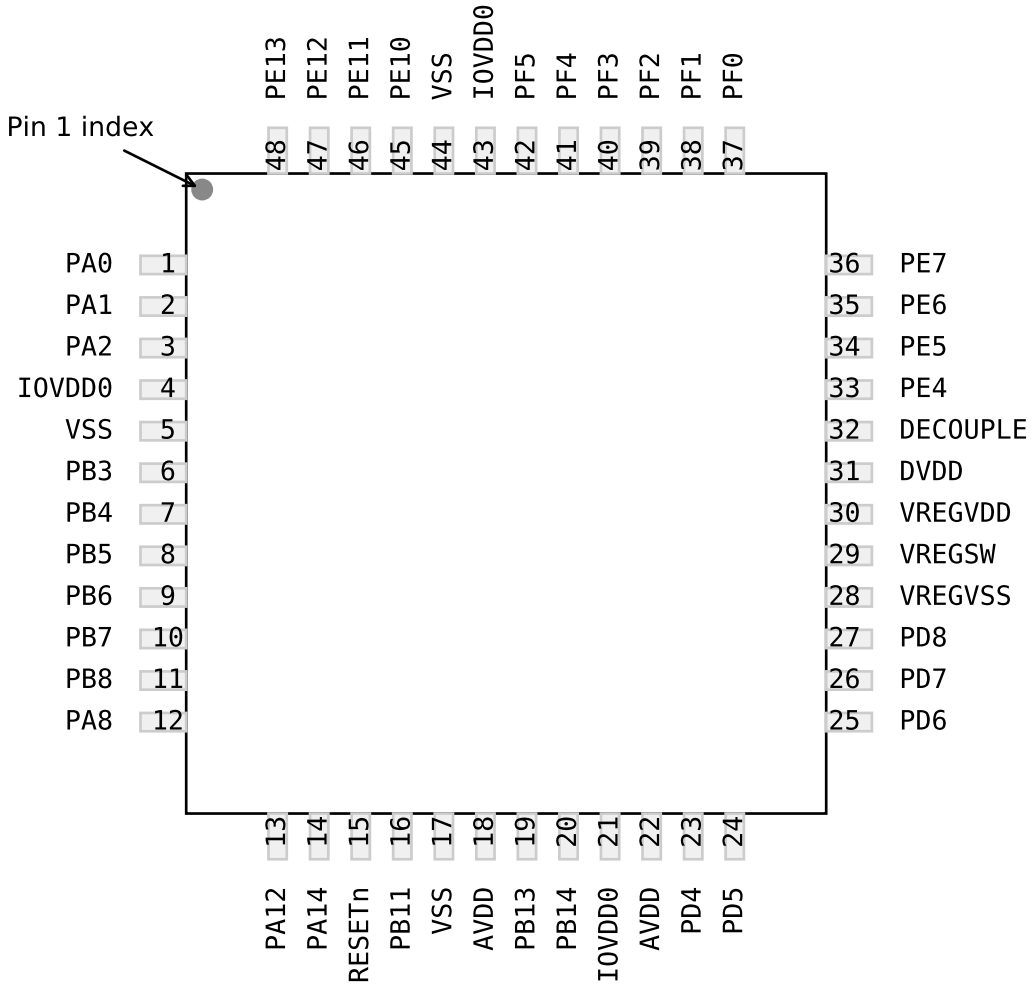


Figure 5.9. EFM32TG11B5xx in QFP48 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.14 GPIO Functionality Table or 5.15 Alternate Functionality Overview.

Table 5.9. EFM32TG11B5xx in QFP48 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	IOVDD0	4 21 43	Digital IO power supply 0.
VSS	5 17 44	Ground	PB3	6	GPIO
PB4	7	GPIO	PB5	8	GPIO
PB6	9	GPIO	PB7	10	GPIO

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PC4	BUSACMP0Y BUSACMP0X OPA0_P LCD_SEG24	TIM0_CC0 #5 TIM0_CDTI2 #3 LETIM0_OUT0 #3	US2_CLK #0 U0_TX #4 I2C1_SDA #0	LES_CH4 GPIO_EM4WU6
PC5	BUSACMP0Y BUSACMP0X OPA0_N LCD_SEG25	TIM0_CC1 #5 LETIM0_OUT1 #3	US2_CS #0 U0_RX #4 I2C1_SCL #0	LES_CH5
PB7	LFXTAL_P	TIM0_CDTI0 #4 TIM1_CC0 #3	US0_TX #4 US1_CLK #0 US3_RX #2 U0_CTS #4	
PB8	LFXTAL_N	TIM0_CDTI1 #4 TIM1_CC1 #3	US0_RX #4 US1_CS #0 U0_RTS #4	CMU_CLKI0 #2
PA8	BU_STAT	TIM0_CC0 #6 LETIM0_OUT0 #6	US2_RX #2	
PA9	BUSAY BUSBX LCD_SEG26	TIM0_CC1 #6 LETIM0_OUT1 #6	US2_CLK #2	
PA10	BUSBY BUSAX LCD_SEG27	TIM0_CC2 #6	US2_CS #2	
PA12	BU_VOUT	WTIM0_CDTI0 #2	US0_CLK #5 US2_RTS #2	CMU_CLK0 #5 ACMP1_O #3
PA13	BUSAY BUSBX	TIM0_CC2 #7 WTIM0_CDTI1 #2	US0_CS #5 US2_TX #3	
PA14	BUSBY BUSAX LCD_BEXT	WTIM0_CDTI2 #2	US1_TX #6 US2_RX #3 US3_RTS #2	ACMP1_O #4
PB11	BUSAY BUSBX VDAC0_OUT0 / OPA0_OUT LCD_SEG28	TIM0_CDTI2 #4 TIM1_CC2 #3 LETIM0_OUT0 #1 PCNT0_S1IN #7	US0_CTS #5 US1_CLK #5 US2_CS #3 I2C1_SDA #1	CMU_CLK1 #5 CMU_CLKI0 #7 ACMP0_O #3 GPIO_EM4WU7
PB12	BUSBY BUSAX VDAC0_OUT1 / OPA1_OUT LCD_SEG29	TIM1_CC3 #3 LETIM0_OUT1 #1 PCNT0_S0IN #7	US2_CTS #1 I2C1_SCL #1	
PB13	BUSAY BUSBX HFXTAL_P	WTIM1_CC0 #0	US0_CLK #4 US1_CTS #5 LEU0_TX #1	CMU_CLKI0 #3 PRS_CH7 #0
PB14	BUSBY BUSAX HFXTAL_N	WTIM1_CC1 #0	US0_CS #4 US1_RTS #5 LEU0_RX #1	PRS_CH6 #1
PD0	VDAC0_OUT0ALT / OPA0_OUTALT #4 OPA2_OUTALT BUSADC0Y BUSADC0X	WTIM1_CC2 #0	CAN0_RX #2 US1_TX #1	
PD1	VDAC0_OUT1ALT / OPA1_OUTALT #4 BUSADC0Y BUSADC0X OPA3_OUT	TIM0_CC0 #2 WTIM1_CC3 #0	CAN0_TX #2 US1_RX #1	
PD2	BUSADC0Y BUSADC0X	TIM0_CC1 #2 WTIM1_CC0 #1	US1_CLK #1	
PD3	BUSADC0Y BUSADC0X OPA2_N LCD_SEG30	TIM0_CC2 #2 WTIM1_CC1 #1	US1_CS #1	
PD4	BUSADC0Y BUSADC0X OPA2_P LCD_SEG31	WTIM0_CDTI0 #4 WTIM1_CC2 #1	US1_CTS #1 US3_CLK #2 LEU0_TX #0 I2C1_SDA #3	CMU_CLKI0 #0

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PD5	BUSADC0Y BUSADC0X OPA2_OUT	WTIM0_CDTI1 #4 WTIM1_CC3 #1	US1_RTS #1 U0_CTS #5 LEU0_RX #0 I2C1_SCL #3	
PD6	BUSADC0Y BUSADC0X ADC0_EXTP VDAC0_EXT OPA1_P	TIM1_CC0 #4 WTIM0_CDTI2 #4 WTIM1_CC0 #2 LE-TIM0_OUT0 #0 PCNT0_S0IN #3	US0_RTS #5 US1_RX #2 US2_CTS #5 US3_CTS #2 U0_RTS #5 I2C0_SDA #1	CMU_CLK2 #2 LES_AL-TEX0 PRS_CH5 #2 ACMP0_O #2
PD7	BUSADC0Y BUSADC0X ADC0_EXTN OPA1_N	TIM1_CC1 #4 WTIM1_CC1 #2 LE-TIM0_OUT1 #0 PCNT0_S1IN #3	US1_TX #2 US3_CLK #1 U0_TX #6 I2C0_SCL #1	CMU_CLK0 #2 LES_AL-TEX1 ACMP1_O #2
PD8	BU_VIN	WTIM1_CC2 #2	US2_RTS #5	CMU_CLK1 #1
PC6	BUSACMP0Y BU-SACMP0X OPA3_P LCD_SEG32	WTIM1_CC3 #2	US0_RTS #2 US1_CTS #3 I2C0_SDA #2	LES_CH6
PC7	BUSACMP0Y BU-SACMP0X OPA3_N LCD_SEG33	WTIM1_CC0 #3	US0_CTS #2 US1_RTS #3 I2C0_SCL #2	LES_CH7
PE4	BUSDY BUSCX LCD_COM0	WTIM0_CC0 #0 WTIM1_CC1 #4	US0_CS #1 US1_CS #5 US3_CS #1 U0_RX #6 I2C0_SDA #7	
PE5	BUSCY BUSDX LCD_COM1	WTIM0_CC1 #0 WTIM1_CC2 #4	US0_CLK #1 US1_CLK #6 US3_CTS #1 I2C0_SCL #7	
PE6	BUSDY BUSCX LCD_COM2	WTIM0_CC2 #0 WTIM1_CC3 #4	US0_RX #1 US3_TX #1	PRS_CH6 #2
PE7	BUSCY BUSDX LCD_COM3	WTIM1_CC0 #5	US0_TX #1 US3_RX #1	PRS_CH7 #2
PC8	BUSACMP1Y BU-SACMP1X LCD_SEG34		US0_CS #2	LES_CH8 PRS_CH4 #0
PC9	BUSACMP1Y BU-SACMP1X LCD_SEG35		US0_CLK #2	LES_CH9 PRS_CH5 #0 GPIO_EM4WU2
PC10	BUSACMP1Y BU-SACMP1X		US0_RX #2	LES_CH10
PC11	BUSACMP1Y BU-SACMP1X		US0_TX #2 I2C1_SDA #4	LES_CH11
PC12	VDAC0_OUT1ALT / OPA1_OUTALT #0 BU-SACMP1Y BUSACMP1X	TIM1_CC3 #0	US0_RTS #3 US1_CTS #4 US2_CTS #4 U0_RTS #3	CMU_CLK0 #1 LES_CH12
PC13	VDAC0_OUT1ALT / OPA1_OUTALT #1 BU-SACMP1Y BUSACMP1X	TIM0_CDTI0 #1 TIM1_CC0 #0 TIM1_CC2 #4 PCNT0_S0IN #0	US0_CTS #3 US1_RTS #4 US2_RTS #4 U0_CTS #3	LES_CH13
PC14	VDAC0_OUT1ALT / OPA1_OUTALT #2 BU-SACMP1Y BUSACMP1X	TIM0_CDTI1 #1 TIM1_CC1 #0 TIM1_CC3 #4 LETIM0_OUT0 #5 PCNT0_S1IN #0	US0_CS #3 US1_CS #3 US2_RTS #3 US3_CS #2 U0_TX #3 LEU0_TX #5	LES_CH14 PRS_CH0 #2

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	CH9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	CH0
OPA3_OUT																																	
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
OPA3_P																																	
APORT1X	BUSAX		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT2X	BUSBX			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT3X	BUSCX												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
APORT4X	BUSDX											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
VDAC0_OUT0 / OPA0_OUT																																	
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				

6.2 TQFP80 PCB Land Pattern

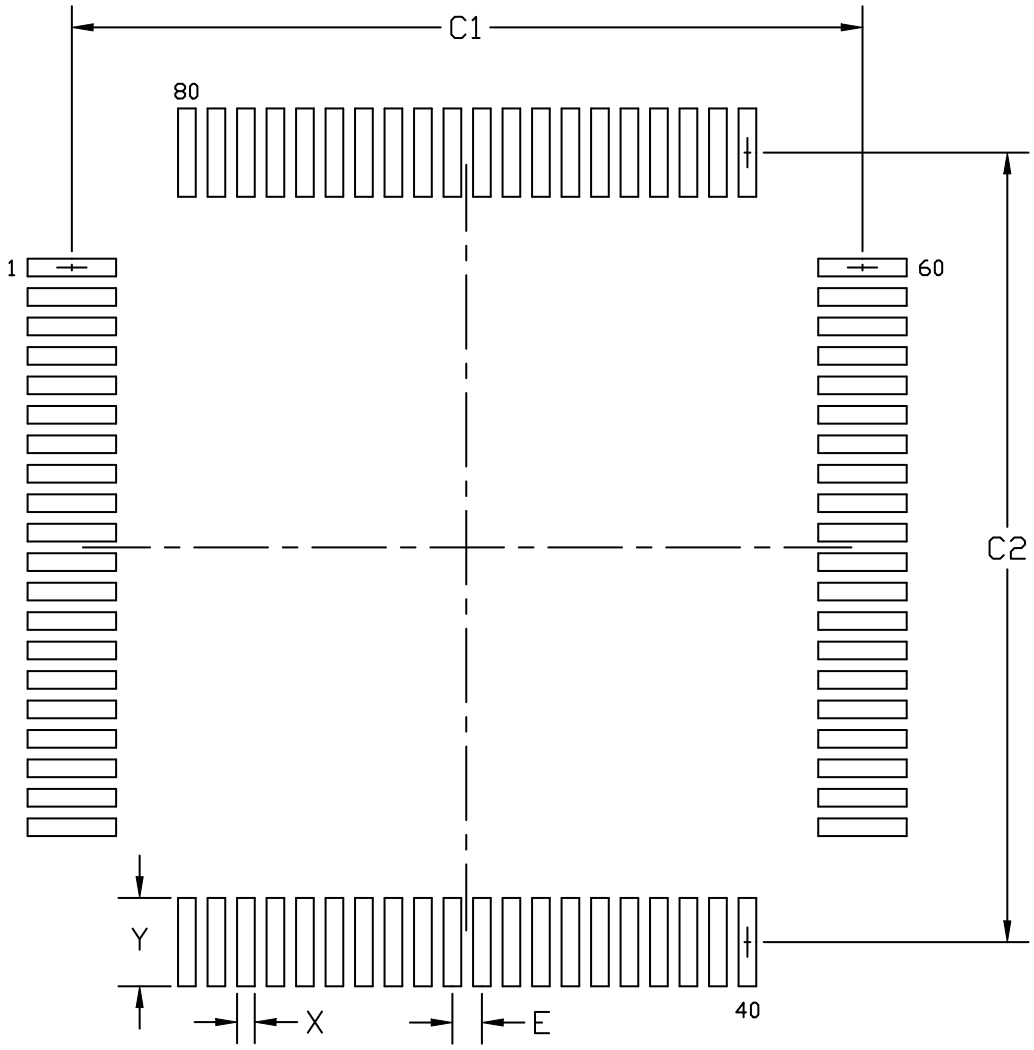


Figure 6.2. TQFP80 PCB Land Pattern Drawing

Table 7.1. QFN80 Package Dimensions

Dimension	Min	Typ	Max
A	0.70	0.75	0.80
A1	0.00	—	0.05
b	0.20	0.25	0.30
A3	0.203 REF		
D	9.00 BSC		
e	0.40 BSC		
E	9.00 BSC		
D2	7.10	7.20	7.30
E2	7.10	7.20	7.30
L	0.35	0.40	0.45
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.05		
eee	0.08		

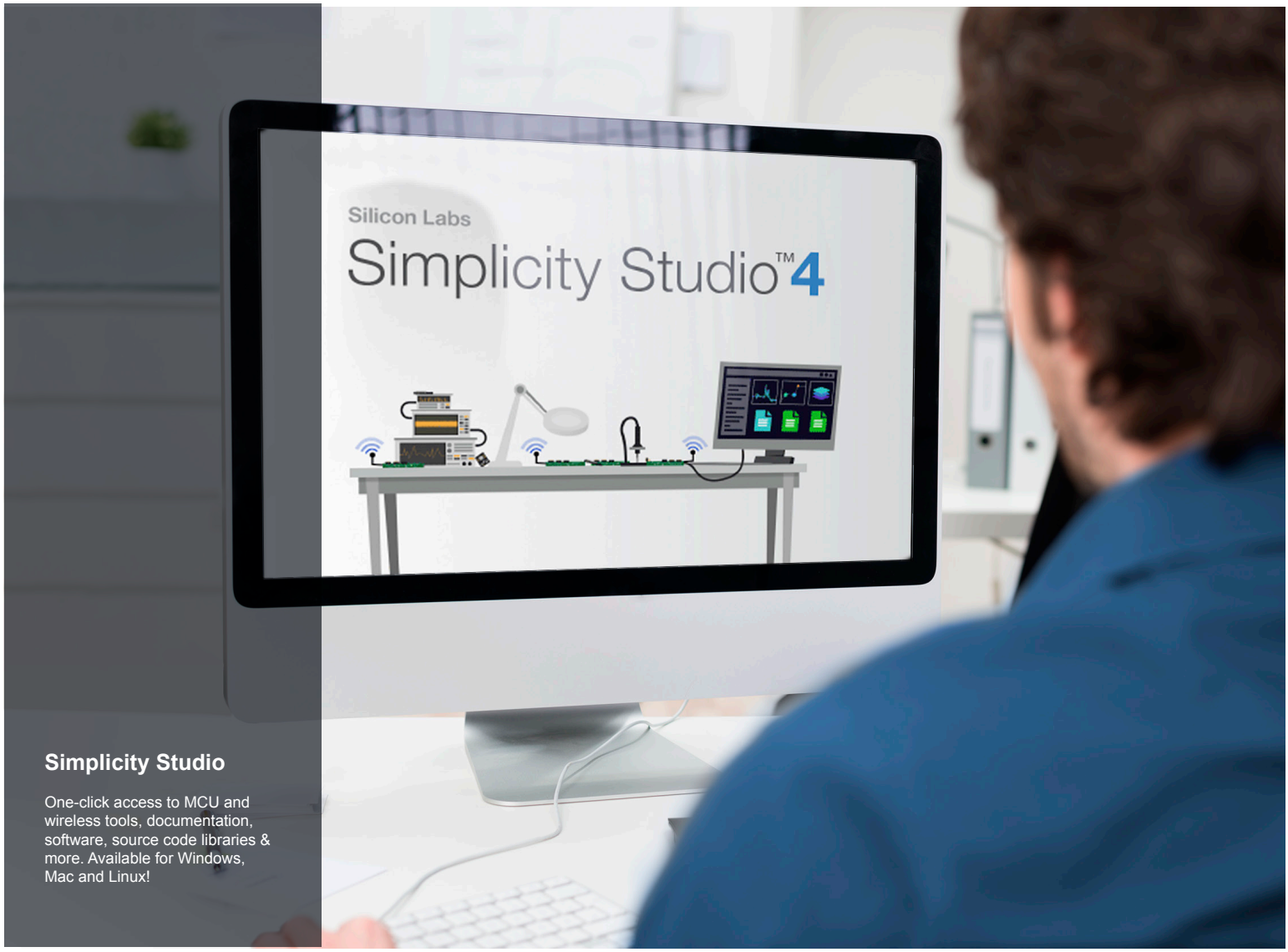
Note:
1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

Table 9.2. QFN64 PCB Land Pattern Dimensions

Dimension	Typ
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	7.30
Y2	7.30

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.
9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



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